

# PR3001G - PR3007G

### 3.0A FAST RECOVERY GLASS PASSIVATED RECTIFIER

#### Features

- Glass Passivated Die Construction
- Diffused Junction
- Fast Switching for High Efficiency
- High Current Capability and Low Forward Voltage Drop
- Surge Overload Rating to 125A Peak
- Low Reverse Leakage Current
- Plastic Material: UL Flammability Classification Rating 94V-0

#### Mechanical Data

- Case: Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: Cathode Band
- Marking: Type Number
- Weight: 1.12 grams (approx.)

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DO-201AD							
Dim	Min	Мах					
Α	25.40	_					
В	7.20	9.50					
С	1.20	1.30					
D	4.80	5.30					
All Dimensions in mm							

#### Maximum Ratings and Electrical Characteristics @ T<sub>A</sub> = 25°C u

**stics** @  $T_A = 25^{\circ}C$  unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic		Symbol	PR 3001G	PR 3002G	PR 3003G	PR 3004G	PR 3005G	PR 3006G	PR 3007G	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage		V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	50	100	200	400	600	800	1000	V
RMS Reverse Voltage		V <sub>R(RMS)</sub>	35	70	140	280	420	560	700	V
Average Rectified Output Current (Note 1)	ied Output Current @ T <sub>A</sub> = 55°C		3.0							А
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave Superimposed on Rated Load (JEDEC Method)		I <sub>FSM</sub>	125						A	
Forward Voltage	@ I <sub>F</sub> = 3.0A	V <sub>FM</sub> 1.3			V					
Peak Reverse Current at Rated DC Blocking Voltage		I <sub>RM</sub>		5.0 100						μA
Reverse Recovery Time (Note 3)		t <sub>rr</sub>	150		250		500		ns	
Typical Junction Capacitance (Note 2)		Cj	50							pF
Typical Thermal Resistance Junction to Ambient		R <sub>0JA</sub>	32							K/W
Operating and Storage Temperature Range		Tj, TSTG	-65 to +150							°C

Notes: 1. Valid provided that leads are maintained at ambient temperature at a distance of 9.5mm from the case.

- 2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.
- 3. Measured with  $I_F$  = 0.5A,  $I_R$  = 1A,  $I_{rr}$  = 0.25A. See figure 5.

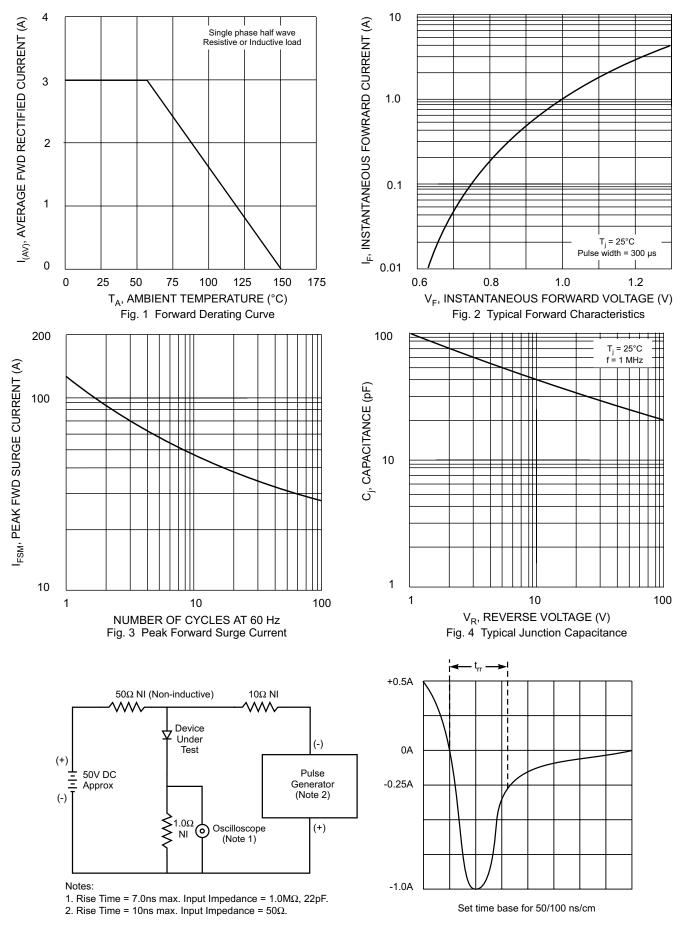


Fig. 5 Reverse Recovery Time Characteristic and Test Circuit